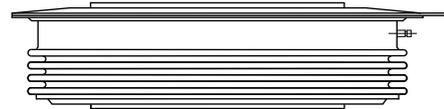


## Phase Control Thyristors (Hockey PUK Version), 3370A

### FEATURES

- Center amplifying gate
- Metal case with ceramic insulator
- International standard case Nell's DX-type Capsule
- Compliant to RoHS
- Low on-state and switching losses
- Designed and qualified for industrial level



Nell's DX-type Capsule

### TYPICAL APPLICATIONS

- DC and AC motor controls
- Controlled DC power supplies
- AC controllers

| PRODUCT SUMMARY |       |
|-----------------|-------|
| $I_{T(AV)}$     | 3370A |

| MAJOR RATINGS AND CHARACTERISTICS |   |              |                   |
|-----------------------------------|---|--------------|-------------------|
| PARAMETER                         | TEST CONDITIONS   | VALUES       | UNIT              |
| $I_{T(AV)}$                       | Double side cooled, single phase, 50Hz, 180° half-sine wave | 3370         | A                 |
|                                   | $T_{hs}$  | 70           | °C                |
| $I_{T(RMS)}$                      |   | 12100        | A                 |
|                                   | $T_{hs}$  | 25           | °C                |
| $I_{TSM}$                         | 50 HZ   | 49000        | kA                |
|                                   | 60 HZ   | 51300        |                   |
| $I^2t$                            | 50 HZ   | 12005        | kA <sup>2</sup> s |
|                                   | 60 HZ   | 10922        |                   |
| $V_{DRM}/V_{RRM}$                 |   | 1200 to 1600 | V                 |
| $T_q$                             | Typical   | 200          | μs                |
| $T_J$                             |   | -40 to 125   | °C                |

### ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS |              |  |  |  |
|-----------------|--------------|--|--|--|
| TYPE NUMBER     | VOLTAGE CODE | $V_{DRM}/V_{RRM}$ , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE<br>V | $V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE<br>V | $I_{DRM}/I_{RRM}$ , MAXIMUM AT $T_J = T_J$ MAXIMUM<br>mA |
| 3370PTxxDX0     | 12           | 1200   | 1300   | 200  |
|                 | 14           | 1400   | 1500   |  |
|                 | 16           | 1600   | 1700   |  |

| FORWARD CONDUCTION                                   |               |  |                          |   |                    |
|--|---------------|--|--------------------------|---|--------------------|
| PARAMETER  | SYMBOL        | TEST CONDITIONS  |                          | VALUES  | UNIT               |
| Maximum average current at heatsink temperature      | $I_{T(AV)}$   | 180° conduction, half sine wave double side (single side) cooled |                          | 3370  | A                  |
|  |               |  |                          | 70  | °C                 |
| Maximum RMS on-state current                         | $I_{T(RMS)}$  | DC at 25°C heatsink temperature double side cooled               |                          | 12800   | A                  |
| Maximum peak, one cycle non-repetitive surge current | $I_{TSM}$     | t = 10ms   | No voltage reapplied     | Sinusoidal half wave, initial $T_J = T_J$ maximum | A                  |
|  |               | t = 8.3ms  |                          |   |                    |
|  |               | t = 10ms   | 100% $V_{RRM}$ reapplied |   |                    |
|  |               | t = 8.3ms  |                          |   |                    |
| Maximum $I^2t$ for fusing                            | $I^2t$        | t = 10ms   | No voltage reapplied     | kA <sup>2</sup> s                                 |                    |
|  |               | t = 8.3ms  |                          |   |                    |
|  |               | t = 10ms   | 100% $V_{RRM}$ reapplied |   |                    |
|  |               | t = 8.3ms  |                          |   |                    |
| Maximum $I^2\sqrt{t}$ for fusing                     | $I^2\sqrt{t}$ | t = 0.1 to 10 ms, no voltage reapplied                           |                          | 120050  | kA <sup>2</sup> √s |
| Maximum threshold voltage                            | $V_{T(TO)}$   | $I_T = 4200A \sim 12500A, T_J = T_J$ maximum                     |                          | 0.94  | V                  |
| Maximum on-state slope resistance                    | $r_t$         |  |                          | 0.066   | mΩ                 |
| Maximum on-state voltage                             | $V_{TM}$      | $I_{pk} = 4000A, T_J = T_J$ maximum, $t_p = 10$ ms sine pulse    |                          | 1.20  | V                  |
| Maximum holding current                              | $I_H$         | $T_J = 25^\circ C$ , anode supply 12V resistive load             |                          | 600   | mA                 |
| Typical latching current                             | $I_L$         |  |                          | 1500  |                    |

| SWITCHING  |          |  |  |        |      |
|--|----------|--|--|--------|------|
| PARAMETER  | SYMBOL   | TEST CONDITIONS  |  | VALUES | UNIT |
| Maximum non-repetitive rate of rise of turned-on current | $di/dt$  | $I_{TM} = 4000A, V_D \leq 80\% V_{DRM}, I_{FG} = 2A, t_r = 0.3\mu s, T_J = T_J$ maximum, $f = 50Hz$                  |  | 200    | A/μs |
| Maximum delay time (Gate turn-on delay time)             | $t_d$    | $V_D = 0.4 V_{DRM}, I_{FG} = 2A, t_r = 0.3\mu s, T_J = 25^\circ C$   |  | 2.0    | μs   |
| Typical turn-on time                                     | $t_g$    | $I_{TM} = 4000A, T_J = T_J$ maximum, $di/dt = -12.5 A/\mu s, V_R = 100V, dV/dt = 50 V/\mu s, V_D \leq 0.67, V_{DRM}$ |  | 200    |      |
| Reverse recovery charge (Typical)                        | $Q_{rr}$ | $I_{TM} = 4000A, T_J = T_J$ maximum, $V_R = 100V, di/dt = -12.5 A/\mu s$   |  | 2800   | μC   |

| BLOCKING   |                    |  |  |        |      |
|--|--------------------|--|--|--------|------|
| PARAMETER  | SYMBOL             | TEST CONDITIONS                                      |  | VALUES | UNIT |
| Minimum critical rate of rise of off-state voltage | $dV/dt$            | $T_J = T_J$ maximum, linear to 67% rated $V_{DRM}$   |  | 1000   | V/μs |
| Maximum peak reverse and off-state leakage current | $I_{RRM}, I_{DRM}$ | $T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied |  | 200    | mA   |

| TRIGGERING                          |             |  |        |      |      |
|-------------------------------------|-------------|--|--------|------|------|
| PARAMETER                           | SYMBOL      | TEST CONDITIONS                              | VALUES |      | UNIT |
|                                     |             |  | TYP.   | MAX. |      |
| Maximum peak gate power             | $P_{GM}$    | $T_J = T_J$ maximum, $t_p \leq 5$ ms         | 25     |      | W    |
| Maximum average gate power          | $P_{G(AV)}$ | $T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$ | 5      |      |      |
| Maximum peak positive gate current  | $I_{GM}$    | $T_J = T_J$ maximum, $t_p \leq 5$ ms         | 10     |      | A    |
| Maximum peak positive gate voltage  | $+V_{GM}$   | $T_J = T_J$ maximum, $t_p \leq 5$ ms         | 12     |      | V    |
| Maximum peak negative gate voltage  | $-V_{GM}$   |  | 10     |      |      |
| DC gate current required to trigger | $I_{GT}$    | $T_J = -40^\circ\text{C}$                    | 200    | 500  | mA   |
|                                     |             | $T_J = 25^\circ\text{C}$                     | 100    | 250  |      |
|                                     |             | $T_J = 125^\circ\text{C}$                    | 50     | 150  |      |
| DC gate voltage required to trigger | $V_{GT}$    | $T_J = -40^\circ\text{C}$                    | 2.5    | 4    | V    |
|                                     |             | $T_J = 25^\circ\text{C}$                     | 1.8    | 3    |      |
|                                     |             | $T_J = 125^\circ\text{C}$                    | 1.1    | 2    |      |
| DC gate current not to trigger      | $I_{GD}$    | $T_J = T_J$ maximum                          | 10     |      | mA   |
| DC gate voltage not to trigger      | $V_{GD}$    |  | 0.25   |      | V    |

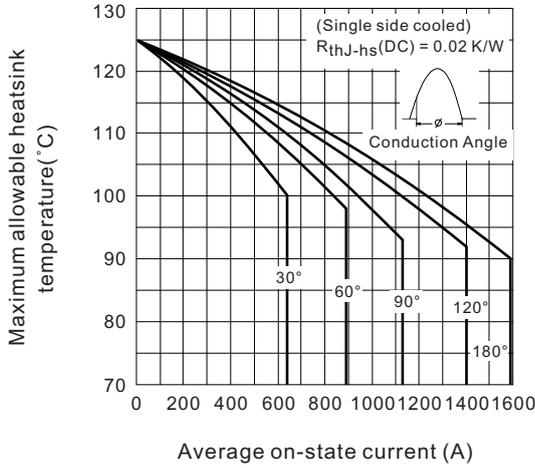
| THERMAL AND MECHANICAL SPECIFICATIONS            |                |                                 |                 |           |  |
|--|----------------|---------------------------------|-----------------|-----------|--|
| PARAMETER  | SYMBOL         | TEST CONDITIONS                 | VALUES          | UNIT      |  |
| Maximum operating junction temperature range     | $T_J$          |                                 | -40 to 125      | °C        |  |
| Maximum storage temperature range                | $T_{stg}$      |                                 | -40 to 150      |           |  |
| Maximum thermal resistance, junction to heatsink | $R_{th(J-hs)}$ | DC operation single side cooled | 0.020           | K/W       |  |
|  |                | DC operation double side cooled | 0.010           |           |  |
| Maximum thermal resistance, case to heatsink     | $R_{th(C-hs)}$ | DC operation single side cooled | 0.006           |           |  |
|  |                | DC operation double side cooled | 0.003           |           |  |
| Mounting force, $\pm 10\%$                       |                |                                 | 50000<br>(5100) | N<br>(kg) |  |
| Approximate weight                               |                |                                 | 930             | g         |  |
| Case style                                       |                | Nell's DX-type Capsule          |                 |           |  |

| $\Delta R_{thJC}$ CONDUCTION |                       |             |                        |             |                     |       |
|------------------------------|-----------------------|-------------|------------------------|-------------|---------------------|-------|
| CONDUCTION ANGEL             | SINUSOIDAL CONDUCTION |             | RECTANGULAR CONDUCTION |             | TEST CONDUCTIONS    | UNITS |
|                              | SINGLE SIDE           | DOUBLE SIDE | SINGLE SIDE            | DOUBLE SIDE |                     |       |
| 180°                         | 0.003                 | 0.003       | 0.002                  | 0.002       | $T_J = T_J$ maximum | K/W   |
| 120°                         | 0.004                 | 0.004       | 0.004                  | 0.004       |                     |       |
| 90°                          | 0.005                 | 0.005       | 0.005                  | 0.005       |                     |       |
| 60°                          | 0.007                 | 0.007       | 0.007                  | 0.007       |                     |       |
| 30°                          | 0.012                 | 0.012       | 0.012                  | 0.012       |                     |       |

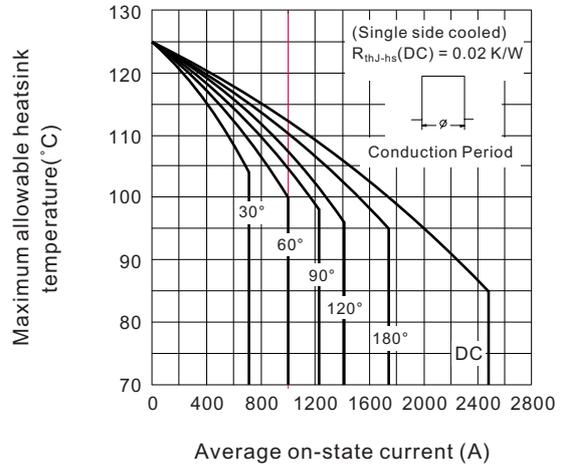
**Note**

- The table above shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC

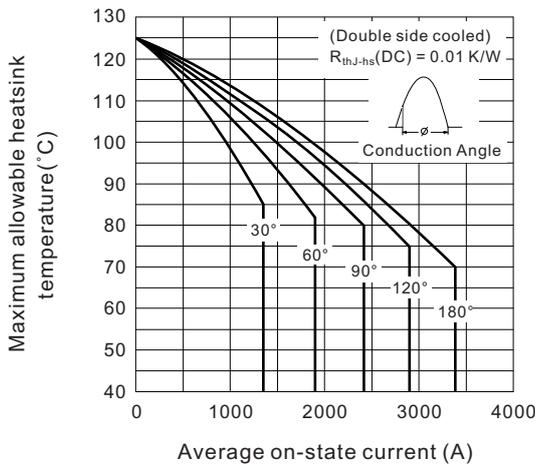
**Fig.1 Current ratings characteristics**



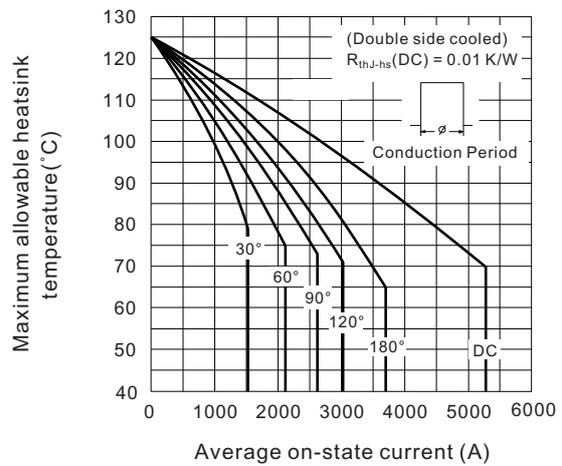
**Fig.2 Current ratings characteristics**



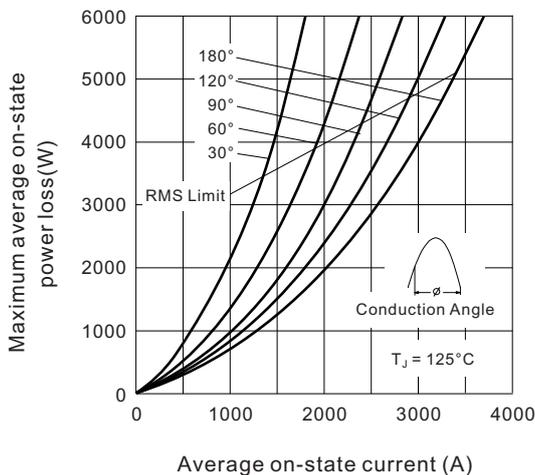
**Fig.3 Current ratings characteristics**



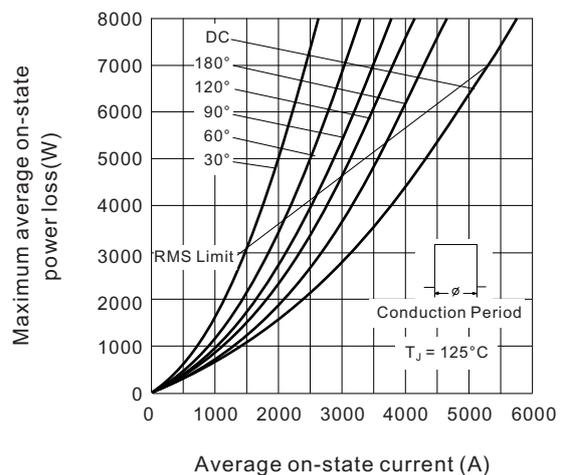
**Fig.4 Current ratings characteristics**



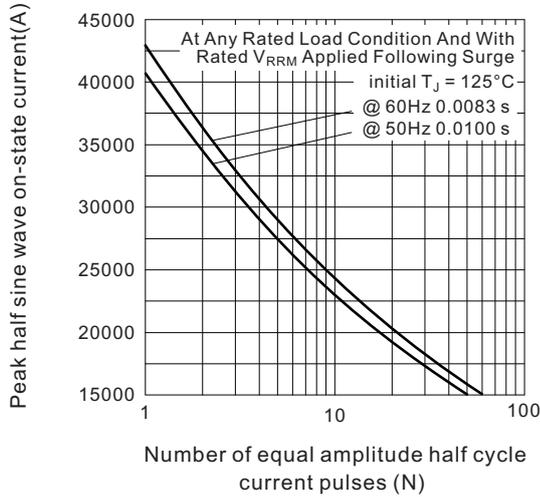
**Fig.5 On-state power loss characteristics**



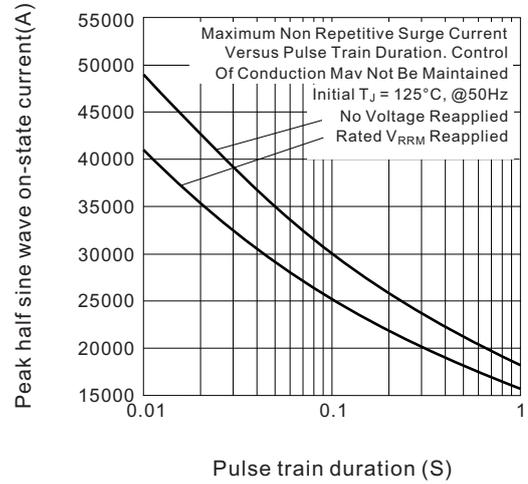
**Fig.6 On-state power loss characteristics**



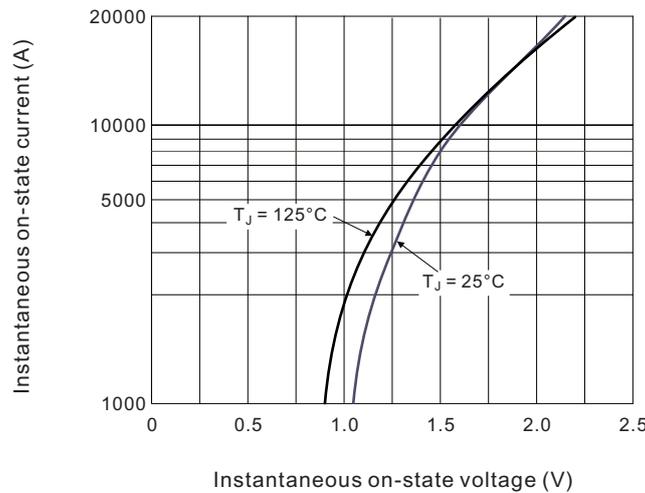
**Fig.7 Maximum non-repetitive surge current single and double side cooled**



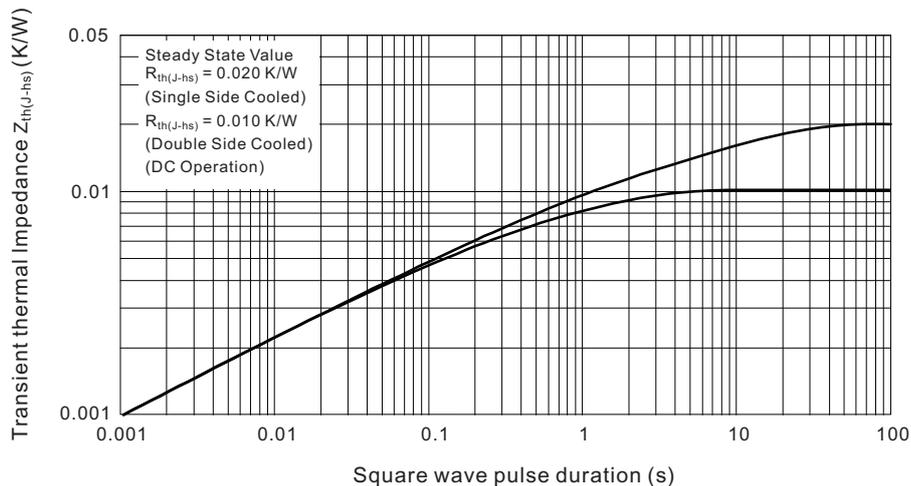
**Fig.8 Maximum non-repetitive surge current single and double side cooled**



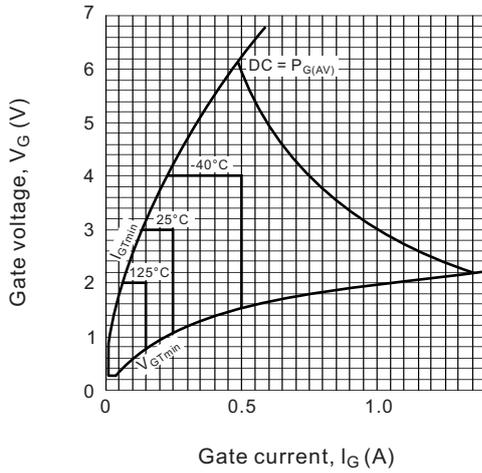
**Fig.9 Maximum on-state voltage drop characteristics**



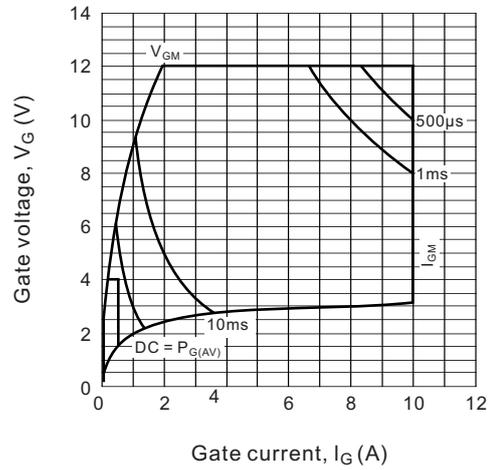
**Fig.10 Thermal Impedance  $Z_{th(J-hs)}$  characteristics**



**Fig.11 Gate trigger characteristics**



**Fig.12 Gate trigger characteristics**

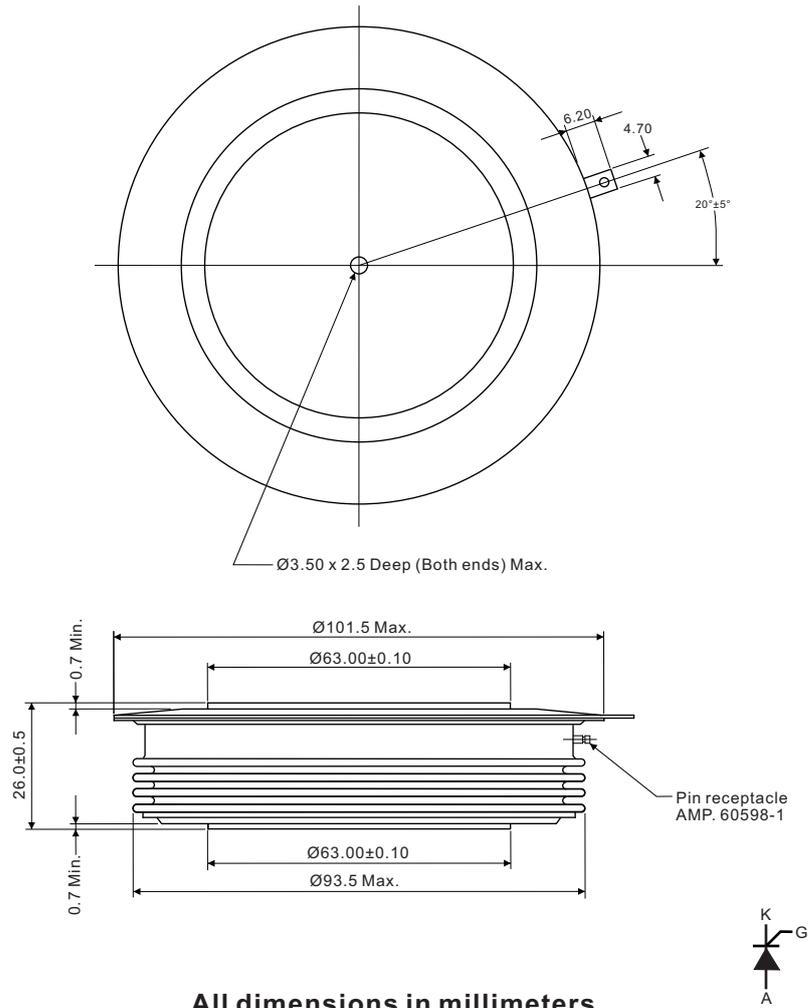


**ORDERING INFORMATION TABLE**

|             |             |           |           |           |          |
|-------------|-------------|-----------|-----------|-----------|----------|
| Device code | <b>3370</b> | <b>PT</b> | <b>16</b> | <b>DX</b> | <b>0</b> |
|             | ①           | ②         | ③         | ④         | ⑤        |

- ① - Maximum average on-state current  $I_{T(AV)}$ , 3370 for 3370A
- ② - PT = Phase control thyristor
- ③ - Voltage code, cold  $\times 100 = V_{RRM}/V_{RRM}$
- ④ - DX = Nell's DX-type Capsule
- ⑤ - Terminal type, "0" for eyelet

**NELL'S DX-type Capsule**



**All dimensions in millimeters**